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Product data sheet

1. General description

Planar passivated four quadrant triac in a SOT78 plastic package intended for use in general purpose bidirectional switching and phase control applications.

2. Features and benefits

- High voltage capability
- Least sensitive gate for highest noise immunity
- High minimum IGT for guaranteed immunity to gate noise
- · Planar passivated for voltage ruggedness and reliability
- Triggering in all four quadrants

3. Applications

- General purpose motor controls
- General purpose switching

4. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; $T_{mb} \le 125 \text{ °C}$; Fig. 1; Fig. 2; Fig. 3	-	-	12	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	95	A
		full sine wave; $T_{j(init)} = 25 \text{ °C};$ t _p = 16.7 ms	-	-	105	A
Tj	junction temperature		-	-	150	°C
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; LD+ G+; T _j = 25 °C; <u>Fig. 7</u>	10	-	50	mA
		V _D = 12 V; I _T = 0.1 A; LD+ G-; T _j = 25 °C; <u>Fig. 7</u>	10	-	50	mA
		V _D = 12 V; I _T = 0.1 A; LD- G-; T _j = 25 °C; <u>Fig. 7</u>	10	-	50	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _i = 25 °C; <u>Fig. 7</u>	10	-	100	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	60	mA
V _T	on-state voltage	I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.65	V
Dynamic cha	racteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	200	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$\label{eq:VD} \begin{array}{l} V_{D} = 400 \; V; \; T_{j} = 150 \; ^{\circ}C; \; I_{T(RMS)} = 12 \; A; \\ dV_{com}/dt = 20 \; V/\mus; \; (snubberless \\ condition); \; gate \; open \; circuit \end{array}$	2	5	-	A/ms

5. Pinning information

Table 2. Pinning information					
Pin	Symbol	Description	Simplified outline	Graphic symbol	
1	T1	main terminal 1	mb	T2-71	
2	T2	main terminal 2		sym051	
3	G	gate		Symoor	
mb	n.c.	mounting base; main terminal 2	TO-220AB (SOT78)		

6. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
BT138-600G0T	TO-220AB	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead TO-220AB	SOT78		

7. Marking

Table 4. Marking codes	
Type number	Marking code
BT138-600G0T	BT138-600G0T

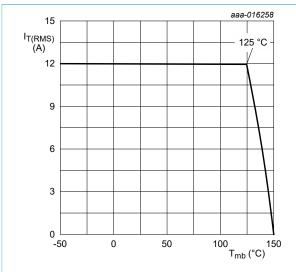
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8. Limiting values

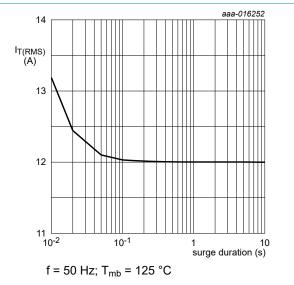
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 125 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	12	A
I _{TSM}	non-repetitive peak on- state current	full sine wave; T _{j(init)} = 25 °C; t _p = 20 ms; <u>Fig. 4; Fig. 5</u>	-	95	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms	-	105	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	45	A²s
dl _T /dt	rate of rise of on-state current	I _G = 0.2 A	-	50	A/µs
		I _G = 0.2 A	-	50	A/µs
		I _G = 0.2 A	-	50	A/µs
		I _G = 0.2 A	-	10	A/µs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	150	°C



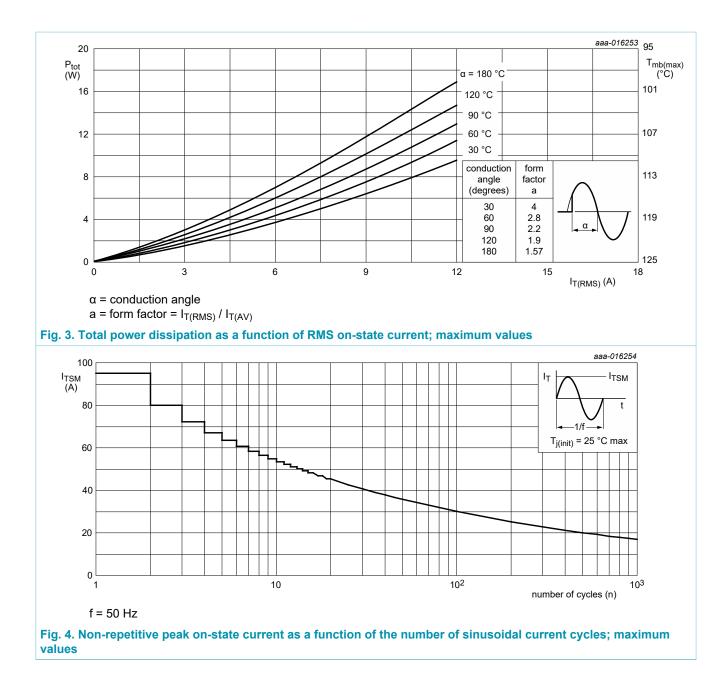






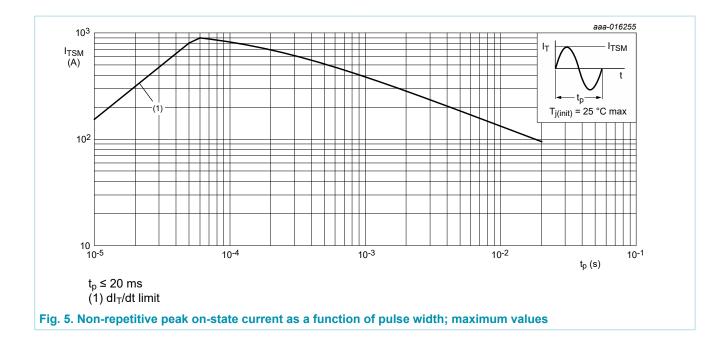
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9. Thermal characteristics

Table 6. Therm	al characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance	full cycle; <u>Fig. 6</u>	-	-	1.5	K/W
	from junction to mounting base	half cycle	-	-	2	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	60	-	K/W

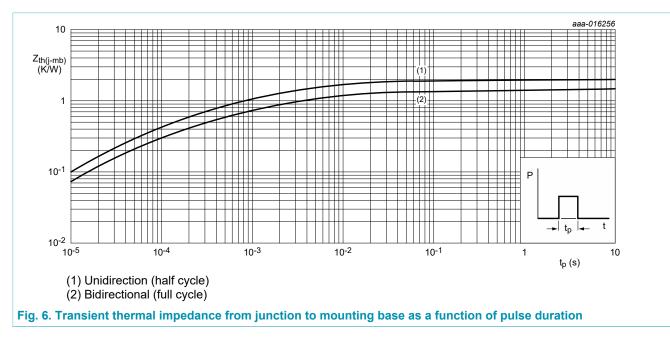


Table 6 Thermal characteristics

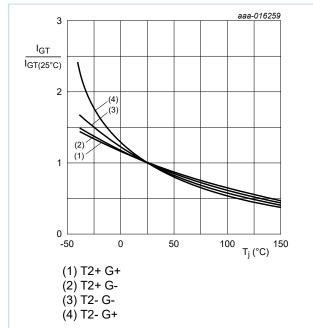
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10. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 0.1 A; LD+ G+; T _j = 25 °C; <u>Fig. 7</u>	10	-	50	mA
		V _D = 12 V; I _T = 0.1 A; LD+ G-; T _j = 25 °C; <u>Fig. 7</u>	10	-	50	mA
		V _D = 12 V; I _T = 0.1 A; LD- G-; T _j = 25 °C; <u>Fig. 7</u>	10	-	50	mA
		V _D = 12 V; I _T = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 7</u>	10	-	100	mA
L	latching current	V _D = 12 V; I _G = 0.1 A; T2+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	60	mA
		V _D = 12 V; I _G = 0.1 A; T2+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	90	mA
		V _D = 12 V; I _G = 0.1 A; T2- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	60	mA
		V _D = 12 V; I _G = 0.1 A; T2- G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	90	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 9</u>	-	-	60	mA
V _T	on-state voltage	I _T = 15 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.4	1.65	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 0.1 A; T _j = 25 °C; <u>Fig. 11</u>	-	0.7	1	V
		V _D = 400 V; I _T = 0.1 A; T _j = 150 °C; <u>Fig. 11</u>	0.25	0.4	-	V
D	off-state current	V _D = 600 V; T _j = 25 °C	-	-	10	μA
		V _D = 600 V; T _j = 150 °C	-	0.4	2	mA
Dynamic ch	aracteristics	·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 150 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit	200	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_D = 400 V; T _j = 150 °C; I _{T(RMS)} = 12 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit	2	5	-	A/ms
t _{gt}	gate-controlled turn-on time	I_{TM} = 16 A; V _D = 600 V; I _G = 0.1 mA; dI _G /dt = 5 A/µs	-	2	-	μs

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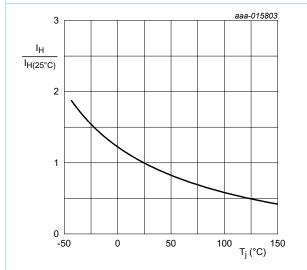
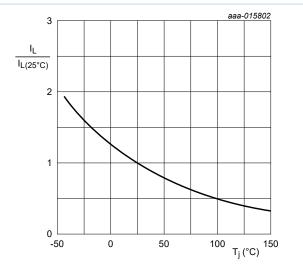
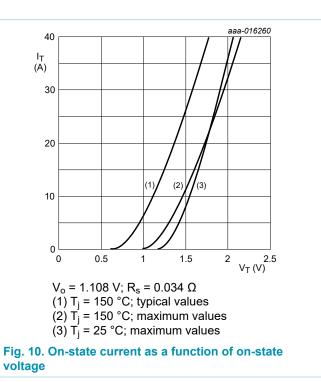


Fig. 9. Normalized holding current as a function of junction temperature

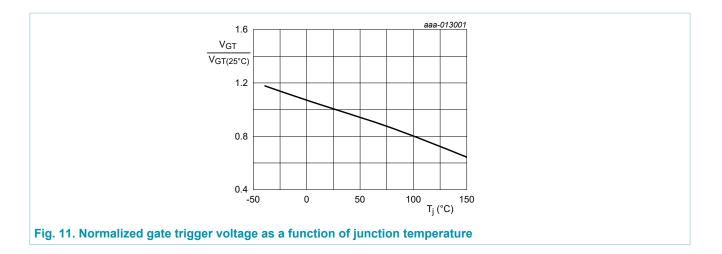






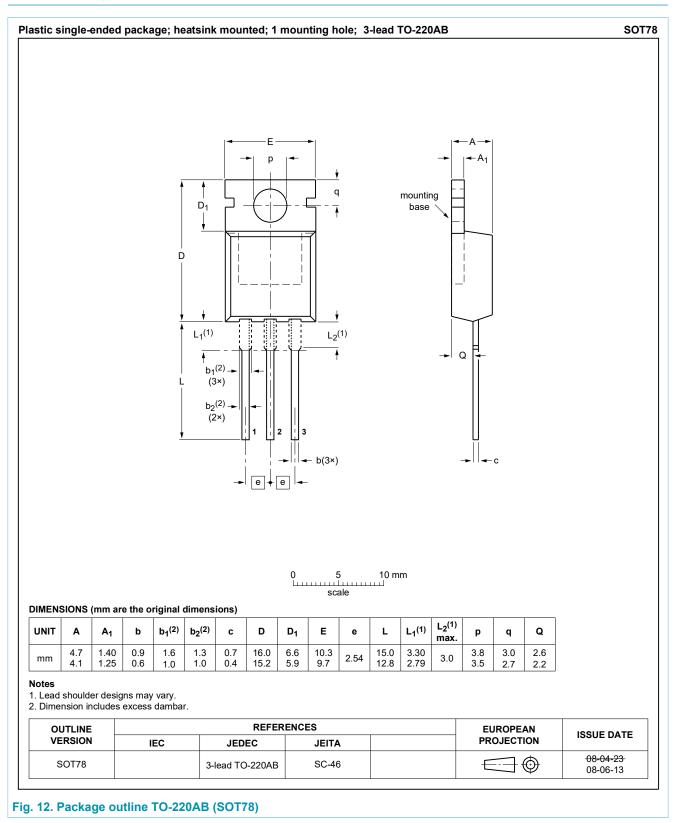
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11. Package outline



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12. Legal information

Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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